# **BTA212 series B**

# GENERAL DESCRIPTION

Glass passivated high commutation triacs in a plastic envelope intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. These devices will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

# **PINNING - TO220AB**

PIN DESCRIPTION		
1	main terminal 1	
2	main terminal 2	
3	gate	
tab	main terminal 2	

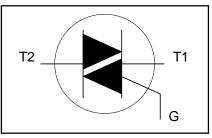
# QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V <sub>drm</sub> I <sub>t(rms)</sub> I <sub>tsm</sub>	BTA212- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	<b>500B</b> 500 12 95	<b>600B</b> 600 12 95	800B 800 12 95	V A A

## PIN CONFIGURATION

tab 🖯

# SYMBOL



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V <sub>DRM</sub>	Repetitive peak off-state voltages		-	<b>-500</b> 500 <sup>1</sup>	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 99 °C	-		12		A
I <sub>TSM</sub>	Non-repetitive peak on-state current	full sine wave; $T_j = 25 \degree C$ prior to surge $t = 20 \ ms$	-		95		A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 16.7 ms t = 10 ms	-		105 45		A A <sup>2</sup> s
dl <sub>⊤</sub> /dt	Repetitive rate of rise of on-state current after triggering	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-		100		Α/μs
I <sub>GM</sub> V <sub>GM</sub> P <sub>GM</sub>	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms	-		2 5 5 0.5		A V W W
P <sub>G(AV)</sub>		period					
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature		-40 -		150 125		ວຸ ວຸ

**<sup>1</sup>** Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

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#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub> R <sub>th j-a</sub>	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air	-	- - 60	1.5 2.0 -	K/W K/W K/W

## STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	2	18	50	mA
			T2+ G-	22	21	50	mA
			T2- G-	2	34	50	mA
IL.	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
-	-		T2+ G+	-	31	60	mA
			T2+ G-	-	34	90	mA
			T2- G-	-	30	60	mA
I <sub>H</sub>	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	31	60	mA
I <sub>H</sub> V <sub>T</sub> V <sub>GT</sub>	On-state voltage	$I_{T} = 17 \text{ A}$		-	1.3	1.6	V
V <sub>GT</sub>	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
-	<b>_</b>	$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 128$	5 °C	0.25	0.4	-	V
I <sub>D</sub>	Off-state leakage current	$V_{\rm D}^{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125 \ ^{\circ}{\rm C}$		-	0.1	0.5	mA

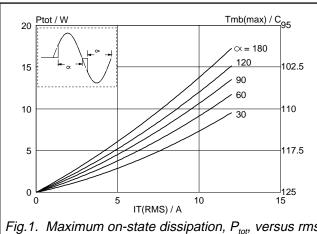
#### **DYNAMIC CHARACTERISTICS**

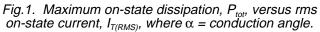
 $T_j = 25$  °C unless otherwise stated

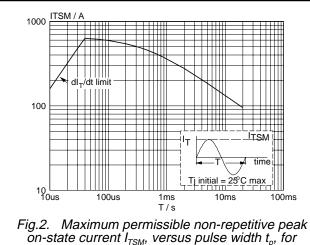
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	1000	4000	-	V/µs
dl <sub>com</sub> /dt	Critical rate of change of	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$	-	24	-	A/ms
t <sub>gt</sub>	commutating current Gate controlled turn-on time	without snubbér; gate open circuit $I_{TM} = 12 \text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 0.1 \text{ A}$ ; $dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs

**<sup>2</sup>** Device does not trigger in the T2-, G+ quadrant.

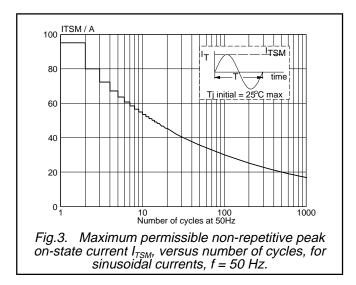
# **BTA212** series B

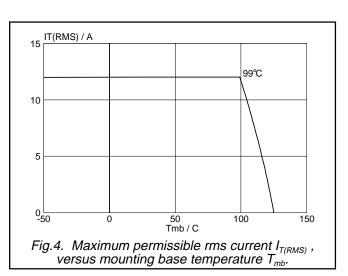






on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \le 20ms$ .





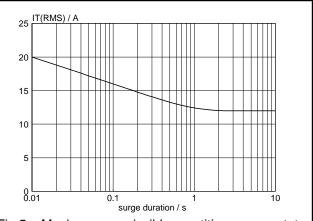
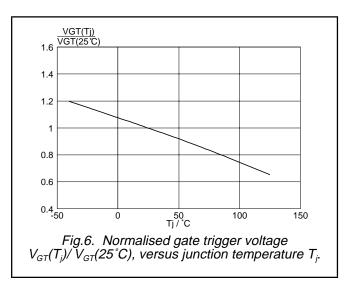
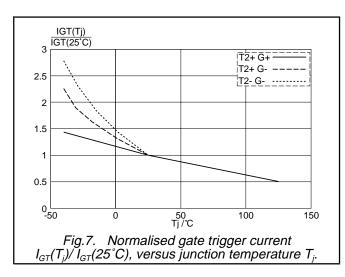
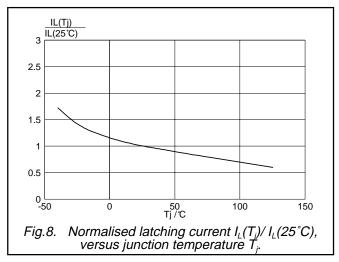


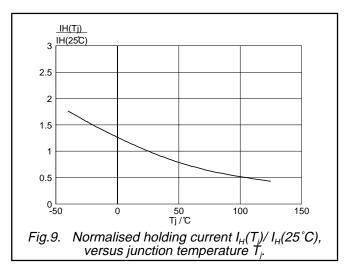
Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 99^{\circ}C$ .

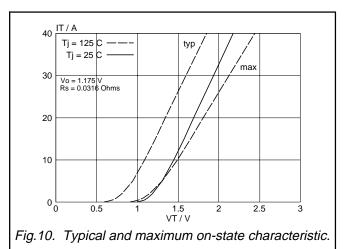


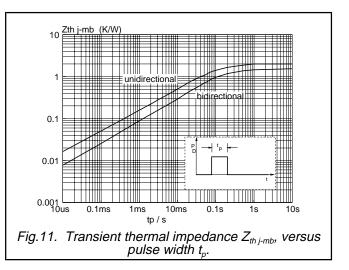
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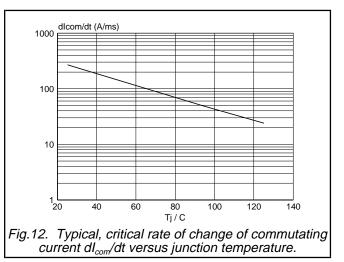








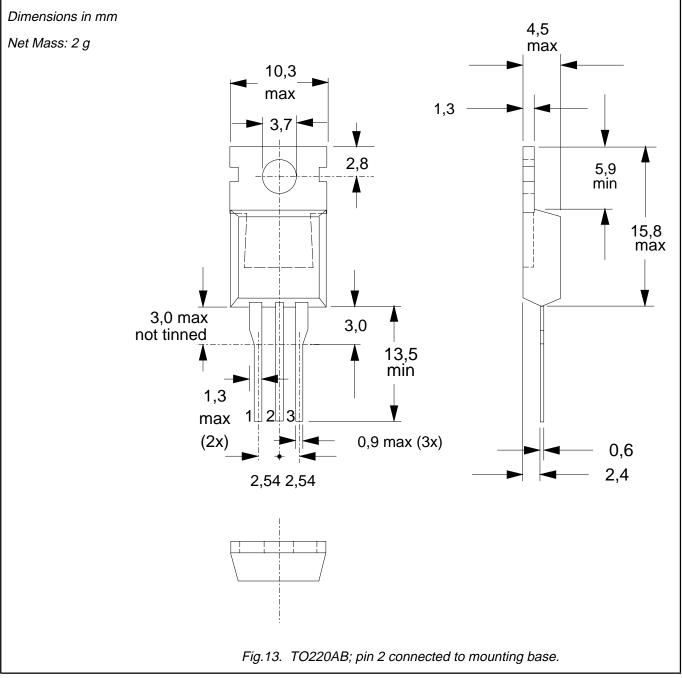




#### Product specification

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#### **MECHANICAL DATA**



**Notes** 1. Refer to mounting instructions for TO220 envelopes. 2. Epoxy meets UL94 V0 at 1/8".

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#### DEFINITIONS

Data sheet status					
Objective specification	bjective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one ues may cause permanent damage to the device. These are stress ratings only and these or at any other conditions above those given in the Characteristics sections of aplied. Exposure to limiting values for extended periods may affect device reliability.				
Application information					
Where application inform	ation is given, it is advisory and does not form part of the specification.				
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